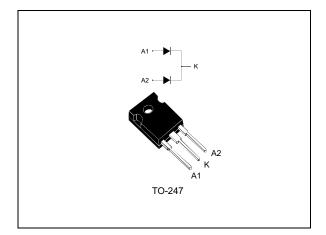


STPS6045C

Power Schottky Rectifier

Datasheet - production data



Features

- Very small conduction losses
- Negligible switching losses
- Extreme fast switching
- Low thermal resistance
- Avalanche capability specified

Description

Dual center tap Schottky rectifier suited for switch mode power supply and high frequency DC to DC converters. Packaged in TO-247, this device is intended for use in low voltage, high frequency inverters, free wheeling and polarity protection applications.

Table 1. Device summary

	-
Symbol	Value
I _F (AV)	2 x 30 A
V _{RRM}	45 V
T _j (max.)	175 °C
V _F (max.)	0.63 V

Characteristics

Symbol	Para	Value	Unit	
V _{RRM}	Repetitive peak reverse volt	age	45	V
I _{F(RMS)}	RMS forward current		60	А
I _{F(AV)}	Average forward current $\delta = 0.5$	Tc = 150 °C per diode	30	А
I _{FSM}	Surge non repetitive forward current tp = 10 ms sinusoidal		400	А
I _{RRM}	Repetive peak reverse current	tp = 2 μs square F = 1 kHz	1	А
I _{RSM}	Non repetitive peak reverse current	tp = 100 μs square	3	А
P _{ARM}	Repetitive peak avalanche power	tp = 1 μs T _j = 25 °C	10600	W
T _{stg}	Storage temperature range	- 65 to + 175	°C	
Тj	Maximum operating junction	175	°C	
dV/dt	Critical rate of rise or reverse	10000	V/µs	

Table 2. Absolute ratings (limiting values, per diode)

1. $\frac{dPtot}{dT_j} < \frac{1}{Rth(j-a)}$ condition to avoid thermal runaway for a diode on its own heatsink

Table 3. thermal resistances

Symbol	Parameter		Value	Unit
R _{th(j-c)}	Junction to case	Per diode Total	0.95 0.55	°C/W
R _{th(c)}		Coupling	0.15	

When the diodes 1 and 2 are simultaneously:

 ΔT_j (diode 1) = P(diode1) x R_{th(j-c)} (Per diode) + P(diode 2) x R_{th(c)}



Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _R ⁽¹⁾	Reverse leakage current	T _j = 25 °C	V _R = V _{RRM}	-		500	μA
		T _j = 125 °C		-	20	80	mA
VF ⁽¹⁾	Forward voltage drop	T _j = 125 °C	IF = 30 A	-	0.53	0.63	
		T _j = 25 °C	IF = 60 A	-		0.84	V
		T _j = 125 °C	IF = 60 A	-	0.68	0.78	

Table 4. Static electrical characteristics (per diode)

1. Pulse test: tp = 380 μ s, δ < 2%

To evaluate the conduction losses use the following equation:

 $P + 0.48 \times I_{F(AV)} + 0.005 I_{F(RMS)}^{2}$

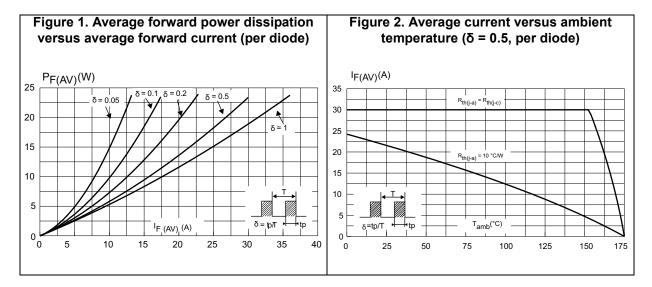
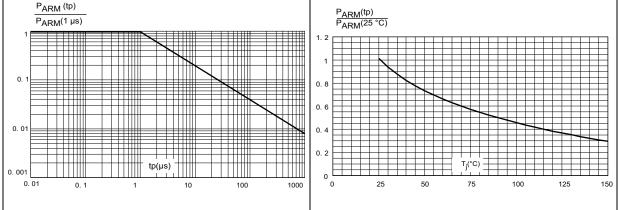
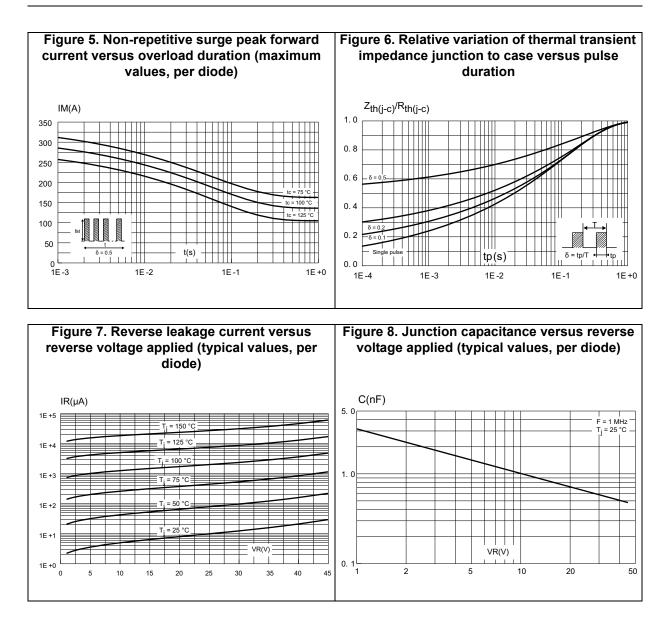


 Figure 3. Normalized avalanche power derating versus pulse duration
 Figure 4. Normalized avalanche power derating versus junction temperature

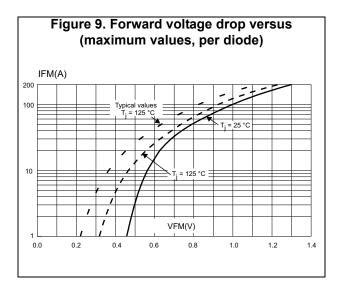
 PARM (tp)
 D
 (tp)













1 Package information

- Cooling method: by conduction (C)
- Recommended torque value: 0.8 N.m.
- Maximum torque value: 1.0 N.m.
- Epoxy meets UL94, V0

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK[®] is an ST trademark.

1.1 TO-247 package information

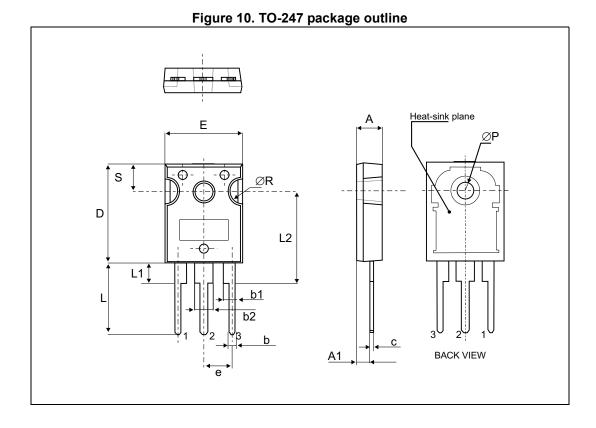




	Table 5. 10-247 package mechanical data					
	Dimensions					
Ref.	Millimeters			Inches ⁽¹⁾		
	Тур.	Min.	Max.	Тур.	Min.	Max.
А		4.85	5.15		0.191	0.203
A1		2.20	2.60		0.086	0.102
b		1.0	1.40		0.039	0.055
b1		2.0	2.40		0.078	0.094
b2		3.0	3.40		0.118	0.133
С		0.40	0.80		0.015	0.031
D		19.85	20.15		0.781	0.793
Е		15.45	15.75		0.608	0.620
е	5.50	5.30	5.60		0.209	0.220
L		14.20	14.80		0.559	0.582
L1		3.70	4.30		0.145	0.169
L2	18.50			0.728		
ØP		3.55	3.65		0.139	0.143
ØR		4.50	5.50		0.177	0.217
S	5.50	5.30	5.70		0.209	0.224

1. Values in inches are converted from mm and rounded to 4 decimal digits.



2 Ordering information

Table 6. Ordering information

Туре	Marking	Package	Weight	Base qty.	Delivery mode
STPS6045CW	STPS6045CW	TO-247	4.36 g.	30	Tube

3 Revision history

Table 7. Document revision history

Date	Revision	Changes
24-Jul-2012	7	
11-Dec-2015	8	Format updated to current standard. Update of <i>Table 2</i> and <i>Table 3</i> and <i>Table 5</i> . Update of <i>Figure 2</i> . Remove of figure 5.2.



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